TOSHIBA

TOSHIBA Photocoupler GaAs Ired & Photo-Triac

TLP165J

Triac Drive Programmable Controllers AC–Output Module Solid State Relay

The TOSHIBA mini flat coupler TLP165J is a small outline coupler, suitable for surface mount assembly. The TLP165J consists of a photo triac, optically coupled to a gallium arsenide infrared emitting diode.

- Peak off-state voltage: 600 V (min.)
- Trigger LED current: 10 mA (max.)
- On-state current: 70 mA (max.)
- Isolation voltage: 2500 Vrms (min.)
- UL recognized: UL1577, file no. E67349
- Option(V4)type

VDE approved: VDE 0884 satisfied Maximum operating insulation voltage: 565Vpk Highest permissible over voltage: 4000Vpk

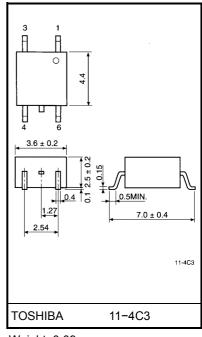
Trigger LED Current

Type (Note 1)	Trigger LED Current (mA)		Marking Of		
	V _T =6V, Ta=25°C		Classification		
	Min.	Max.	Olassilication		
(IFT7)		7	Т7		
None		10	T7, blank		

* Exp. rank IFT7: TLP165J (IFT7)

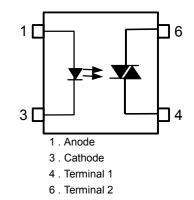
(Note 1) Application type name for certification test, please use standard product type name, i.e.

TLP165J(IFT7): TLP165J



Weight: 0.09 g

Pin Configurations



Unit in mm

Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit	
LED	Forward current		١ _F	50	mA	
	Forward current derating (Ta ≥ 5	ΔI _F / °C	-0.7	mA / °C		
	Peak forward current (100µs pul	I _{FP}	1	А		
	Reverse voltage	V _R	5	V		
	Junction temperature	Tj	125	°C		
	Off- state output terminal voltage	V _{DRM}	600	V		
	On-state RMS current	Ta=25°C		70	mA	
		Ta=70°C	I _{T(RMS)}	40	IIIA	
Detector	On–state current derating (Ta ≥	ΔI _T / °C	-0.67	mA / °C		
Det	Peak on-state current (100µs pu	I _{TP}	2	A		
	Peak nonrepetitive surge current (PW=10ms, DC=10%)	I _{TSM}	1.2	А		
	Junction temperature	Tj	115	°C		
Storage temperature range			T _{stg}	-55~125	°C	
Operating temperature range			T _{opr}	-40~100	°C	
Lead soldering temperature (10s)			T _{sol}	260	°C	
Isolation voltage (AC, 1 min., R.H. \leq 60%) (Note 2)			BVS	2500	Vrms	

(Note 2) Device considered a two terminal device: Pins 1 and 3 shorted together and 4 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V _{AC}	_	_	240	Vac
Forward current	١ _F	15	20	25	mA
Peak on-state current	I _{TP}	_	_	1	А
Operating temperature	T _{opr}	-25		85	°C

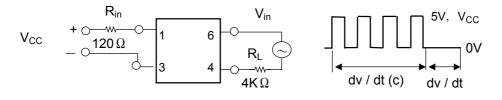
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
LED	Forward voltage	V _F	I _F =10mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R =5V	_	_	10	μA
	Capacitance	CT	V=0, f=1MHz	_	30	-	pF
Detector	Peak off-state current	I _{DRM}	V _{DRM} =600V	_	10	1000	nA
	Peak on-state voltage	V _{TM}	I _{TM} =70mA	_	1.7	2.8	V
	Holding current	Ι _Η	—	_	1.0	_	mA
	Critical rate of rise of off-state voltage	dv / dt	V _{in} =240Vrms, Ta=85°C (Note 3)	_	500	_	V / µs
	Critical rate of rise of commutating voltage	dv / dt(c)	I _T =15mA, V _{in} =60Vrms (Note 3)	_	0.2	_	V / µs

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	V _T =6V	_	_	10	mA
Capacitance input to output	Cs	V _S =0, f=1MHz	—	0.8	_	pF
Isolation resistance	R _S	V _S =500V, R.H. ≤ 60%	1×10 ¹²	10 ¹⁴	_	Ω
	BVS	AC, 1 minute	2500	_	_	Vrms
Isolation voltage		AC, 1 second, in oil	—	5000	_	
		DC, 1 minute, in oil	—	5000	_	Vdc
Turn–on time	t _{ON}	V _D =6→4V, R _L = 100Ω I _F =Rated I _{FT} ×1.5	_	_	100	μs

(Note 3) dv / dt test circuit



RESTRICTIONS ON PRODUCT USE

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